



EPAD™ ULTRA MICROPOWER OPERATIONAL AMPLIFIER

KEY FEATURES

- EPAD (Electrically Programmable Analog Device)
- User programmable V_{OS} trimmer
- Computer-assisted trimming
- Rail-to-rail input/output
- Compatible with standard EPAD Programmer
- High precision through in-system circuit precision trimming
- Reduces or eliminates V_{OS} , PSRR, CMRR and TCV_{OS} errors
- System level “calibration” capability
- Application-Specific Programming mode
- In-System Programming mode
- Electrically programmable to compensate for external component tolerances
- Achieves 0.01pA input bias current and 50 μ V input offset voltage simultaneously
- Compatible with industry standard pinout

GENERAL DESCRIPTION

The ALD1726E/ALD1726 is a monolithic rail-to-rail ultra-micropower precision CMOS operational amplifier with integrated user programmable EPAD (Electrically Programmable Analog Device) based offset voltage adjustment. The ALD1726E/ALD1726 is a direct replacement of the ALD1706 operational amplifier, with the added feature of user-programmable offset voltage trimming resulting in significantly enhanced total system performance and user flexibility. EPAD technology is an exclusive ALD design which has been refined for analog applications where precision voltage trimming is necessary to achieve a desired performance. It utilizes CMOS FETs as in-circuit elements for trimming of offset voltage bias characteristics with the aid of a personal computer under software control. Once programmed, the set parameters are stored indefinitely within the device even after power-down. EPAD offers the circuit designer a convenient and cost-effective trimming solution for achieving the very highest amplifier/system performance.

The ALD1726E/ALD1726 operational amplifier features rail-to-rail input and output voltage ranges, tolerance to over-voltage input spikes of 300mV beyond supply rails, extremely low input currents of 0.01pA typical, high open loop voltage gain, useful bandwidth of 200KHz, slew rate of 0.17 V/ μ s, and low typical supply current of 25 μ A.

ORDERING INFORMATION

Operating Temperature Range		
-55°C to +125°C	0°C to +70°C	0°C to +70°C
8-Pin CERDIP Package	8-Pin Small Outline Package (SOIC)	8-Pin Plastic Dip Package
ALD1726E DA ALD1726 DA	ALD1726E SA ALD1726 SA	ALD1726E PA ALD1726 PA

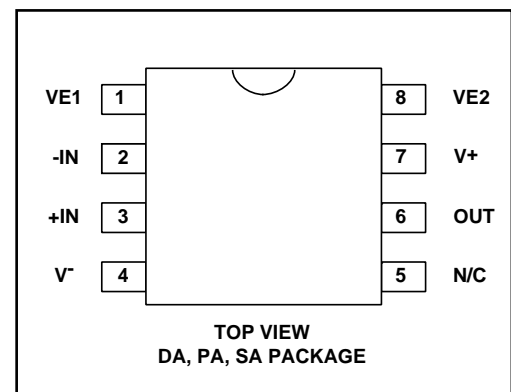
BENEFITS

- Eliminates manual and elaborate system trimming procedures
- Remote controlled automated trimming
- In-System Programming capability
- No external components
- No internal chopper clocking noise
- No chopper dynamic power dissipation
- Simple and cost effective
- Small package size
- Extremely small total functional volume size
- Low system implementation cost
- Micropower and Low Voltage

APPLICATIONS

- Sensor interface circuits
- Transducer biasing circuits
- Capacitive and charge integration circuits
- Biochemical probe interface
- Signal conditioning
- Portable instruments
- High source impedance electrode amplifiers
- Precision Sample and Hold amplifiers
- Precision current to voltage converter
- Error correction circuits
- Sensor compensation circuits
- Precision gain amplifiers
- Periodic In-system calibration
- System output level shifter

PIN CONFIGURATION



* Contact factory for industrial temperature range

FUNCTIONAL DESCRIPTION

The ALD1726E/ALD1726 uses EPADs as in-circuit elements for trimming of offset voltage bias characteristics. Each ALD1726E/ALD1726 has a pair of EPAD-based circuits connected such that one circuit is used to adjust V_{OS} in one direction and the other circuit is used to adjust V_{OS} in the other direction.

Functional Description of ALD1726E

While each of the EPAD devices is a monotonically adjustable programmable device, the V_{OS} of the ALD1726E can be adjusted many times in both directions. Once programmed, the set V_{OS} levels are stored permanently, even when the device power is removed.

The ALD1726E provides the user with an operational amplifier that can be trimmed with user application-specific programming or in-system programming conditions. User application-specific circuit programming refers to the situation where the Total Input Offset Voltage of the ALD1726E (V_{OST}) can be trimmed with the actual intended operating conditions.

The ALD1726E is pre-programmed at the factory under standard operating conditions for minimum equivalent input offset voltage. It also has a guaranteed offset voltage program range, which is ideal for applications that require electrical offset voltage programming.

For example, an application circuit may have +6V and -2.5V power supplies, and the operational amplifier input is biased at +0.7V, and the average operating temperature is at 55°C. The circuit can be wired up to these conditions within an environmental chamber, and the ALD1726E can be inserted into a test socket connected to this circuit while it is being electrically trimmed. Any error in V_{OS} due to these bias conditions can be automatically zeroed out. The Total V_{OS} error is now limited only by the adjustable range and the stability of V_{OS} , and the input noise voltage of the operational amplifier. Therefore, this Total V_{OS} error now includes V_{OS} as V_{OS} is traditionally specified; plus the V_{OS} error contributions from PSRR, CMRR, TCV_{OS} , and noise. Typically this total V_{OS} error term (V_{OST}) is approximately $\pm 50\mu V$ for the ALD1726E.

The V_{OS} contribution due to PSRR, CMRR, TCV_{OS} and external components can be large for operational amplifiers without trimming. Therefore the ALD1726E with EPAD trimming is able to provide much improved system performance by reducing these other sources of error to provide significantly reduced V_{OST} .

In-System Programming refers to the condition where the EPAD adjustment is made after the ALD1726E has been inserted into a circuit board. In this case, the circuit design must provide for the ALD1726E to operate in normal mode and in programming mode. One of the benefits of in-system programming is that not only is the ALD1726E offset voltage from operating bias conditions accounted for, any residual errors introduced by other circuit components, such as resis-

tor or sensor induced voltage errors, can also be corrected. In this way, the "in-system" circuit output can be adjusted to a desired level eliminating other trimming components.

Functional Description of ALD1726

The ALD1726 is pre-programmed at the factory under standard operating conditions for minimum equivalent input offset voltage. The ALD1726 offers similar programmable features as the ALD1726E, but with more limited offset voltage program range. It is intended for standard operational amplifier applications where little or no electrical programming by the user is necessary.

USER PROGRAMMABLE V_{OS} FEATURE

Each ALD1726E/ALD1726 has two pins named VE1 and VE2 which are internally connected to an internal offset bias circuit. VE1/VE2 have initial typical values of 1.0 to 1.5 Volt. The voltage on these pins can be programmed using the ALD E100 EPAD Programmer and the appropriate Adapter Module. The useful programming range of VE1 and VE2 is 1.2 Volt to 3.0 Volts. VE1 and VE2 pins are programming pins, used during programming mode. The Programming pin is used during electrical programming to inject charge into the internal EPADs. Increases of VE1 decrease the offset voltage while increases of VE2 increase the offset voltage of the operational amplifier. The injected charge is permanently stored and determines the offset voltage of the operational amplifier. After programming, VE1 and VE2 terminals must be left open to settle on a voltage determined by internal bias currents.

During programming, the voltages on VE1 or VE2 are increased incrementally to set the offset voltage of the operational amplifier to the desired V_{OS} . Note that desired V_{OS} can be any value within the offset voltage programmable ranges, and can be either zero, a positive value or a negative value. This V_{OS} value can also be reprogrammed to a different value at a later time, provided that the useful VE1 or VE2 programming voltage range has not been exceeded. VE1 or VE2 pins can also serve as capacitively coupled input pins.

Internally, VE1 and VE2 are programmed and connected differentially. Temperature drift effects between the two internal offset bias circuits cancel each other and introduce less net temperature drift coefficient change than offset voltage trimming techniques such as offset adjustment with an external trimmer potentiometer.

While programming, V_+ , VE1 and VE2 pins may be alternately pulsed with 12V (approximately) pulses generated by the EPAD Programmer. In-system programming requires the ALD1726E/ALD1726 application circuit to accommodate these programming pulses. This can be accomplished by adding resistors at certain appropriate circuit nodes. For more information, see Application Note AN1700.

ABSOLUTE MAXIMUM RATINGS

Supply voltage, V+ _____ 13.2V
 Differential input voltage range _____ -0.3V to V+ +0.3V
 Power dissipation _____ 600 mW
 Operating temperature range PA,SA package _____ 0°C to +70°C
 DA package _____ -55°C to +125°C
 Storage temperature range _____ -65°C to +150°C
 Lead temperature, 10 seconds _____ +260°C

OPERATING ELECTRICAL CHARACTERISTICS

TA = 25°C VS = ±2.5V unless otherwise specified

Parameter	Symbol	1726E			1726			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max		
Supply Voltage	VS	±1.0		±5.0	±1.0		±5.0	V	Single Supply
	V+	2.0		10.0	2.0		10.0	V	
Initial Input Offset Voltage ¹	VOS _i		50	100		75	150	μV	RS ≤ 100KΩ
Offset Voltage Program Range ²	ΔVOS	±10	±20		±1	±5		mV	
Programmed Input Offset Voltage Error ³	VOS		50	100		75	150	μV	At user specified target offset voltage
Total Input Offset Voltage ⁴	VOST		50	100		75	150	μV	At user specified target offset voltage
Input Offset Current ⁵	IOS		0.01	10 240		0.01	10 240	pA pA	TA = 25°C 0°C ≤ TA ≤ +70°C
Input Bias Current ⁵	IB		0.01	10		0.01	10	pA	TA = 25°C
Input Voltage Range ⁶	VIR	-0.3 -2.8		5.3 +2.8	-0.3 -2.8		5.3 +2.8	V V	V+ = +5V VS = ±2.5V
Input Resistance	R _{IN}		10 ¹⁴			10 ¹⁴		Ω	
Input Offset Voltage Drift ⁷	TCVOS		7			7		μV/°C	RS ≤ 100KΩ
Initial Power Supply Rejection Ratio ⁸	PSRR _i		80			80		dB	RS ≤ 100KΩ
Initial Common Mode Rejection Ratio ⁸	CMRR _i		83			83		dB	RS ≤ 100KΩ
Large Signal Voltage Gain	Av	32 20	100		32 20	100		V/mV V/mV	RL = 1MΩ 0°C ≤ TA ≤ +70°C
Output Voltage Range	VO low VO high	4.99	0.001 4.999	0.01	4.99	0.001 4.999	0.01	V V	RL = 1MΩ V+ = 5V 0°C ≤ TA ≤ +70°C
	VO low VO high	2.40	-2.48 2.48	-2.40	2.40	-2.48 2.48	-2.40	V V	RL = 100KΩ 0°C ≤ TA ≤ +70°C
Output Short Circuit Current	ISC		200			200		μA	

* NOTES 1 through 9, see section titled "Definitions and Design Notes".

OPERATING ELECTRICAL CHARACTERISTICS (cont'd)

T_A = 25°C V_S = ±2.5V unless otherwise specified

Parameter	Symbol	1726E			1726			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max		
Supply Current	I _S		25	40		25	40	μA	V _{IN} = 0V No Load
Power Dissipation	P _D			200			200	μW	V _S = ±2.5V
Input Capacitance	C _{IN}		1			1		pF	
Maximum Load Capacitance	C _L		25			25		pF	
Equivalent Input Noise Voltage	e _n		55			55		nV/√Hz	f = 1KHz
Equivalent Input Current Noise	i _n		0.6			0.6		fA/√Hz	f = 10Hz
Bandwidth	BW		400			400		KHz	
Slew Rate	S _R		0.17			0.17		V/μs	A _V = +1 R _L = 1MΩ
Rise time	t _r		1.0			1.0		μs	R _L = 1MΩ
Overshoot Factor			20			20		%	R _L = 1MΩ, C _L = 25pF
Settling Time	t _s		10			10		μs	0.1% A _V = 1, R _L = 1MΩ C _L = 25pF

T_A = 25°C V_S = ±2.5V unless otherwise specified

Parameter	Symbol	1726E			1726			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max		
Average Long Term Input Offset Voltage Stability ^a	$\frac{\Delta V_{OS}}{\Delta \text{time}}$		0.02			0.02		μV/ 1000 hrs	
Initial VE Voltage	VE1 _i , VE2 _i		1.0			1.5		V	
Programmable VE Range	ΔVE1, ΔVE2	1.0	2.0			0.5		V	
Programmed VE Voltage Error	e(VE1-VE2)		0.1			0.1		%	
VE Pin Leakage Current	i _{eb}		-5			-5		μA	

$V_S = \pm 2.5V$ $-55^\circ C \leq T_A \leq +125^\circ C$ unless otherwise specified

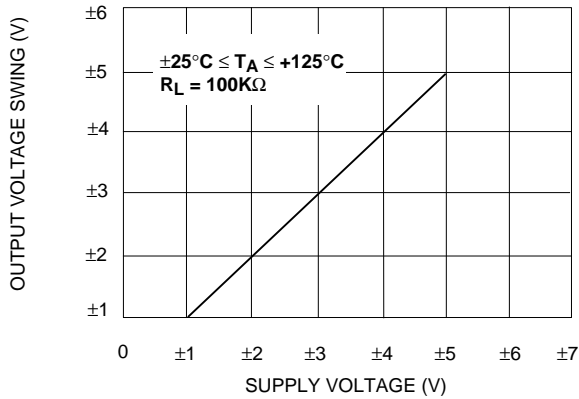
Parameter	Symbol	1726E			1726			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max		
Initial Input offset Voltage	V_{OSi}		0.7			0.7		mV	$R_S \leq 100K\Omega$
Input Offset Current	I_{OS}			2.0			2.0	nA	
Input Bias Current	I_B			2.0			2.0	nA	
Initial Power Supply Rejection Ratio ⁸	$PSRR_i$		75			75		dB	$R_S \leq 1M\Omega$
Initial Common Mode Rejection Ratio ⁸	$CMRR_i$		83			83		dB	$R_S \leq 1M\Omega$
Large Signal Voltage Gain	A_V	15	50		15	50		V/mV	$R_L = 1M\Omega$
Output Voltage Range	$V_{O\ low}$ $V_{O\ high}$	2.30	-2.40 2.40	-2.30	2.30	-2.40 2.40	-2.30	V V	$R_L = 1M\Omega$

$T_A = 25^\circ C$ $V_S = \pm 1.0V$ unless otherwise specified

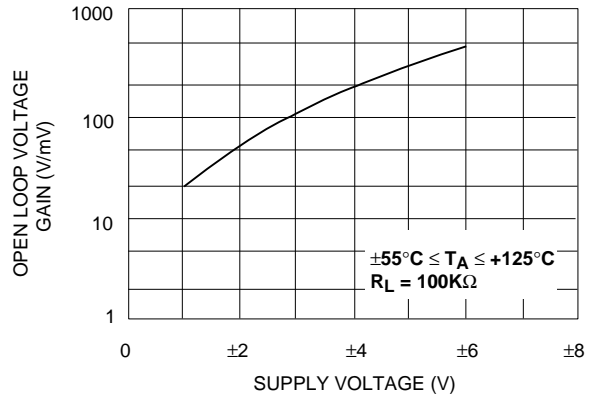
Parameter	Symbol	1726E			1726			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max		
Initial Power Supply Rejection Ratio ⁸	$PSRR_i$		70			70		dB	$R_S \leq 1M\Omega$
Initial Common Mode Rejection Ratio ⁸	$CMRR_i$		70			70		dB	$R_S \leq 1M\Omega$
Large Signal Voltage Gain	A_V		50			50		V/mV	$R_L = 1M\Omega$
Output Voltage Range	$V_{O\ low}$ $V_{O\ high}$	0.9	-0.95 0.95	-0.9	0.90	-0.95 0.95	-0.90	V	$R_L = 1M\Omega$
Bandwidth	BW		0.3			0.3		MHz	
Slew Rate	S_R		0.17			0.17		V/ μs	$A_V = +1, C_L = 50pF$

TYPICAL PERFORMANCE CHARACTERISTICS

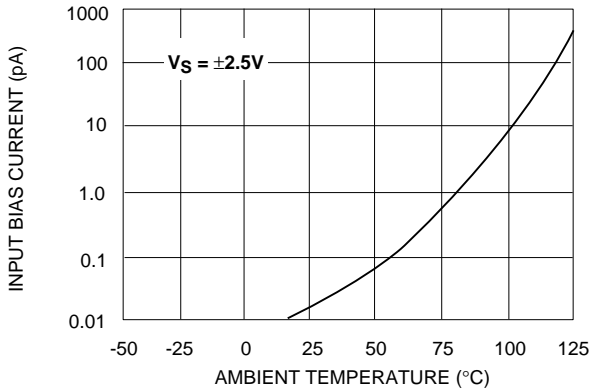
OUTPUT VOLTAGE SWING AS A FUNCTION OF SUPPLY VOLTAGE



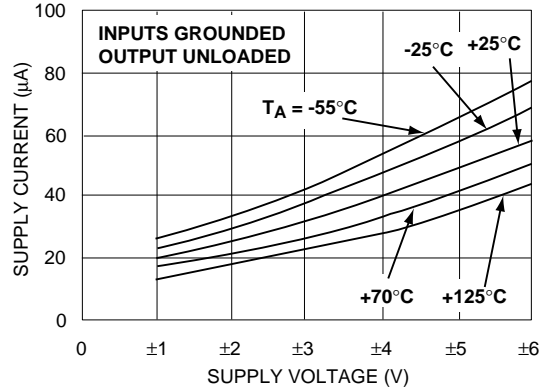
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF SUPPLY VOLTAGE AND TEMPERATURE



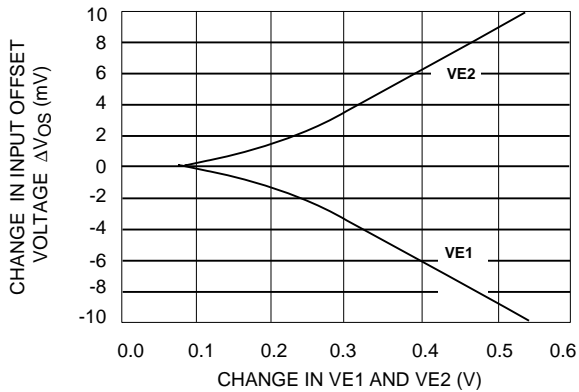
INPUT BIAS CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE



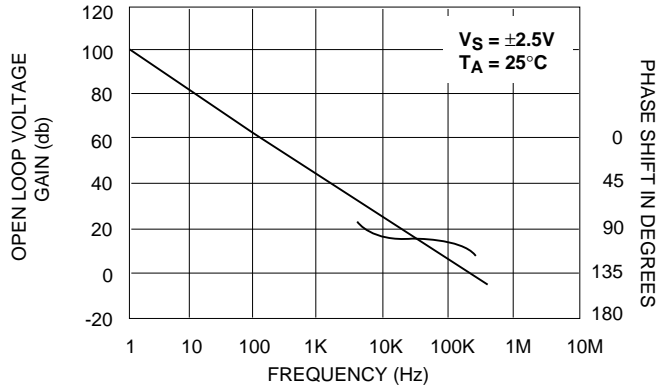
SUPPLY CURRENT AS A FUNCTION OF SUPPLY VOLTAGE



ADJUSTMENT IN INPUT OFFSET VOLTAGE AS A FUNCTION OF CHANGE IN VE1 AND VE2

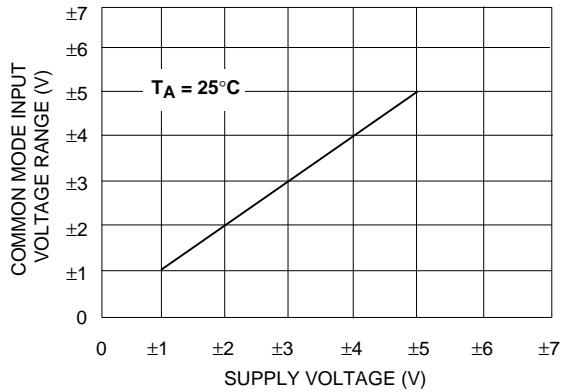


OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF FREQUENCY

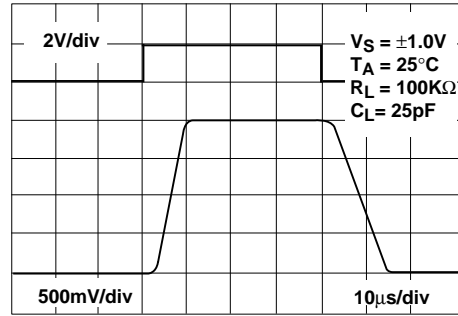


TYPICAL PERFORMANCE CHARACTERISTICS

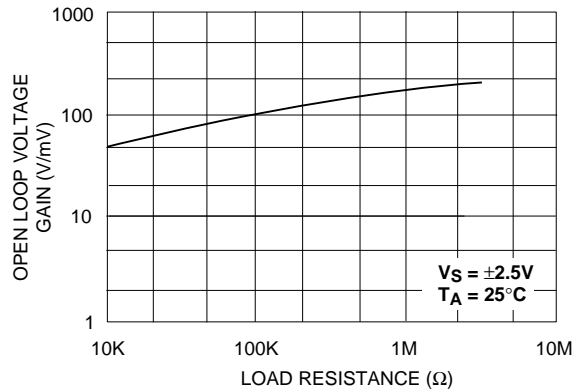
COMMON MODE INPUT VOLTAGE RANGE AS A FUNCTION OF SUPPLY VOLTAGE



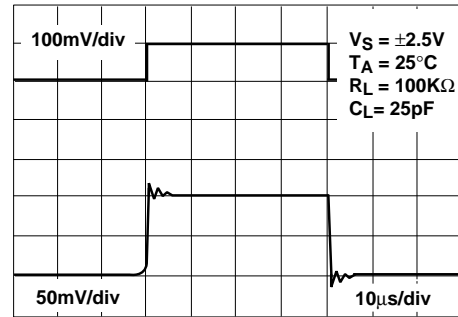
LARGE - SIGNAL TRANSIENT RESPONSE



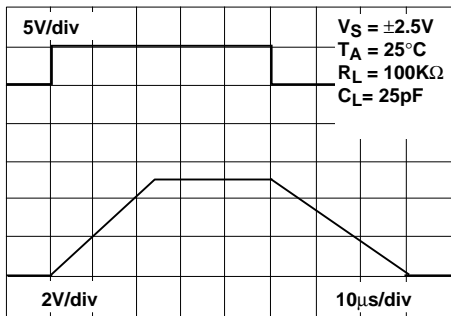
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF LOAD RESISTANCE



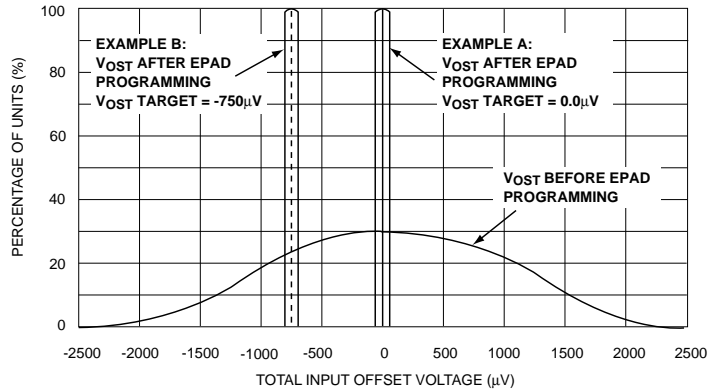
SMALL - SIGNAL TRANSIENT RESPONSE

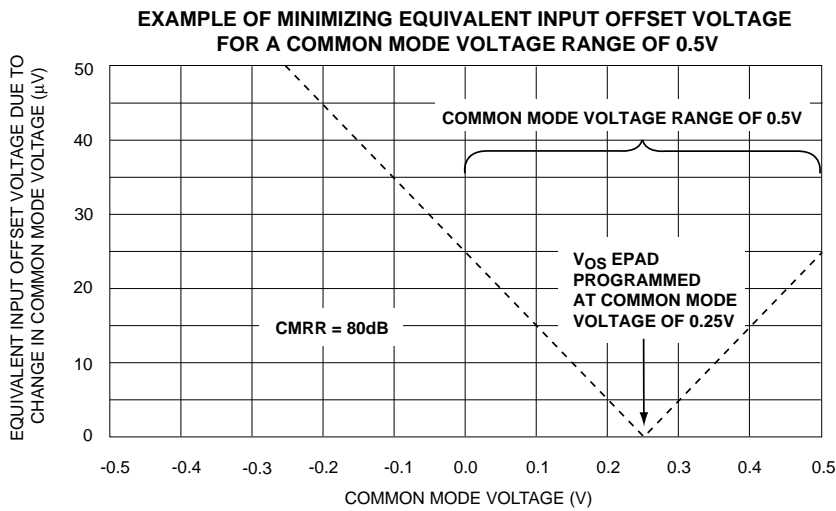
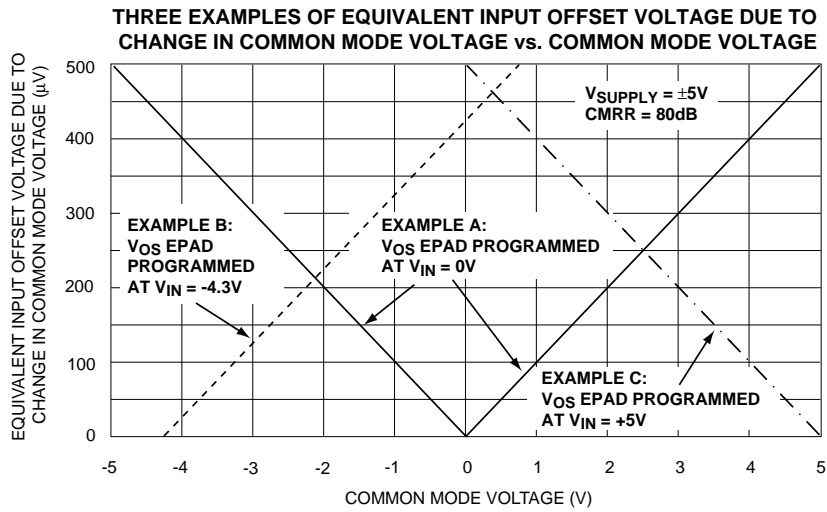
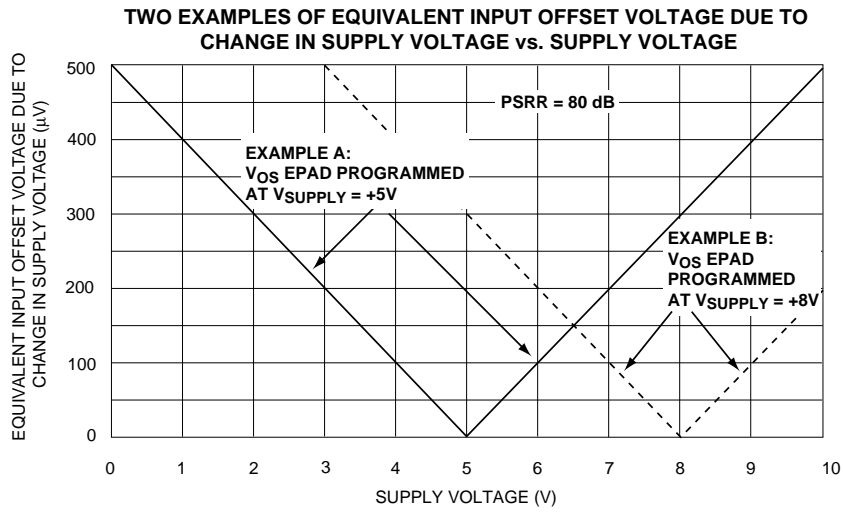


LARGE - SIGNAL TRANSIENT RESPONSE



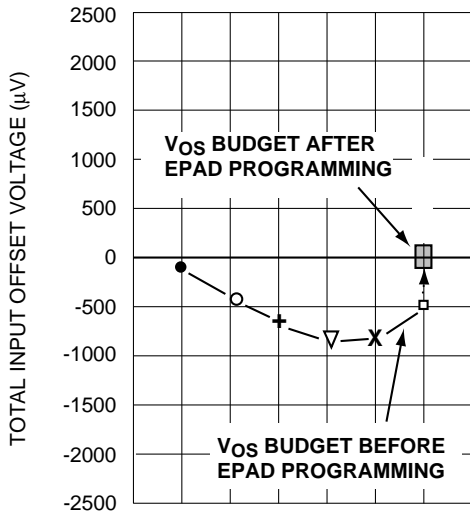
DISTRIBUTION OF TOTAL INPUT OFFSET VOLTAGE BEFORE AND AFTER EPAD PROGRAMMING



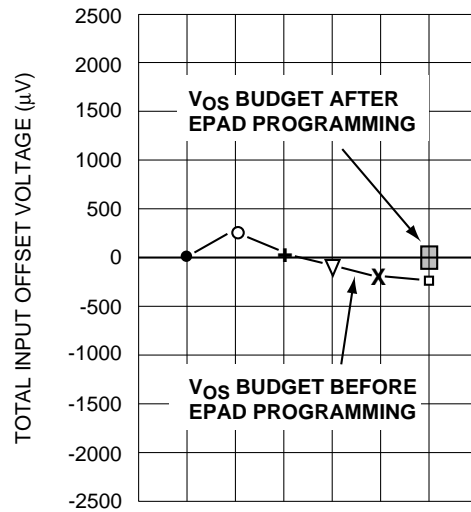


APPLICATION SPECIFIC / IN-SYSTEM PROGRAMMING

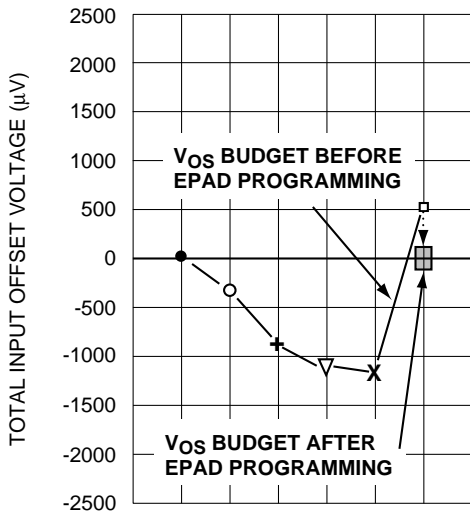
Examples of applications where accumulated total input offset voltage from various contributing sources is minimized under different sets of user-specified operating conditions



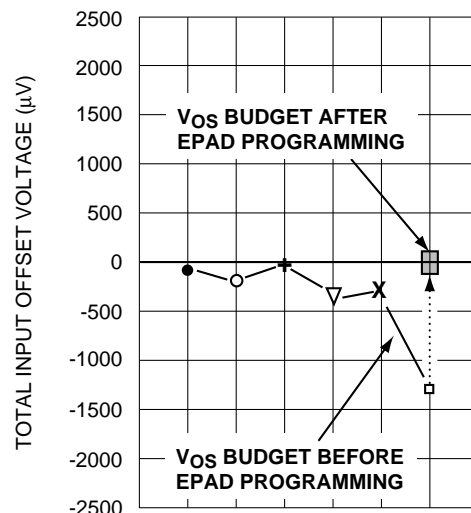
EXAMPLE A



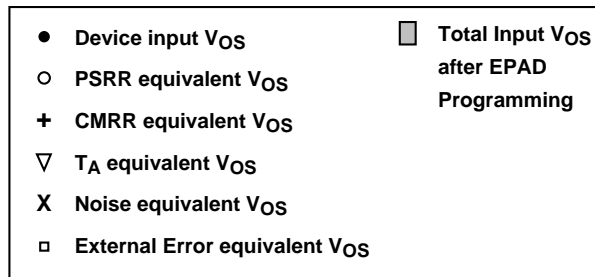
EXAMPLE B



EXAMPLE C



EXAMPLE D



DEFINITIONS AND DESIGN NOTES:

1. Initial Input Offset Voltage is the initial offset voltage of the ALD1726E/ALD1726 operational amplifier when shipped from the factory. The device has been pre-programmed and tested for programmability.

2. Offset Voltage Program Range is the range of adjustment of user specified target offset voltage. This is typically an adjustment in either the positive or the negative direction of the input offset voltage from an initial input offset voltage. The input offset programming pins, VE1 or VE2, change the input offset voltage in the negative or positive direction, respectively. User specified target offset voltage can be any offset voltage within this programming range.

3. Programmed Input Offset Voltage Error is the final offset voltage error after programming when the Input Offset Voltage is at target Offset Voltage. This parameter is sample tested.

4. Total Input Offset Voltage is the same as Programmed Input Offset Voltage, corrected for system offset voltage error. Usually this is an all inclusive system offset voltage, which also includes offset voltage contributions from input offset voltage, PSRR, CMRR, TC_{VOS} and noise. It can also include errors introduced by external components, at a system level. Programmed Input Offset Voltage and Total Input Offset Voltage is not necessarily zero offset voltage, but an offset voltage set to compensate for other system errors as well. This parameter is sample tested.

5. The Input Offset and Bias Currents are essentially input protection diode reverse bias leakage currents. This low input bias current assures that the analog signal from the source will not be distorted by it. For applications where source impedance is very high, it may be necessary to limit noise and hum pickup through proper shielding.

6. Input Voltage Range is determined by two parallel complementary input stages that are summed internally, each stage having a separate input offset voltage. While Total Input Offset Voltage can be trimmed to a desired target value, it is essential to note that this trimming occurs at only one user selected input bias voltage. Depending on the selected input bias voltage relative to the power supply voltages, offset voltage trimming may affect one or both input stages. For the ALD1726E/ALD1726, the switching point between the two stages occur at approximately 1.5V below positive supply voltage.

7. Input Offset Voltage Drift is the average change in Total Input Offset Voltage as a function of ambient temperature. This parameter is sample tested.

8. Initial PSRR and initial CMRR specifications are provided as reference information. After programming, error contribution to the offset voltage from PSRR and CMRR is set to zero under the specific power supply and common mode conditions, and becomes part of the Programmed Input Offset Voltage Error.

9. Average Long Term Input Offset Voltage Stability is based on input offset voltage shift through operating life test at 125°C extrapolated to $T_A = 25\text{ }^\circ\text{C}$, assuming activation energy of 1.0eV. This parameter is sample tested.

ADDITIONAL DESIGN NOTES:

A. The ALD1726E/ALD1726 is internally compensated for unity gain stability using a novel scheme which produces a single pole roll off in the gain characteristics while providing more than 60 degrees of phase margin at unity gain frequency. A unity gain buffer using the ALD1726E/ALD1726 will typically drive 25pF of external load capacitance.

B. The ALD1726E/ALD1726 has complementary p-channel and n-channel input differential stages connected in parallel to accomplish rail-to-rail input common mode voltage range. The switching point between the two differential stages is 1.5V below positive supply voltage. For applications such as inverting amplifier or non-inverting amplifier with a gain larger than 2.5 (5V operation), the common mode voltage does not make excursions below this switching point. However, this switching does take place if the operational amplifier is connected as a rail-to-rail unity gain buffer and the design must allow for input offset voltage variations.

C. The output stage consists of class AB complementary output drivers. The oscillation resistant feature, combined with the rail-to-rail input and output feature, makes the ALD1726E/ALD1726 an effective analog signal buffer for high source impedance sensors, transducers, and other circuit networks.

D. The ALD1726E/ALD1726 has static discharge protection. Care must be exercised when handling the device to avoid strong static fields that may degrade a diode junction, causing increased input leakage currents. The user is advised to power up the circuit before, or simultaneously with, any input voltages applied and to limit input voltages not to exceed 0.3V of the power supply voltage levels.

E. VE1 and VE2 are high impedance terminals, as the internal bias currents are set very low to a few microamperes to conserve power. For some applications, these terminals may need to be shielded from external coupling sources. For example, digital signals running nearby may cause unwanted offset voltage fluctuations. Care during the printed circuit board layout to place ground traces around these pins and to isolate them from digital lines will generally eliminate such coupling effects. In addition, optional decoupling capacitors of 1000pF or greater value can be added to VE1 and VE2 terminals.

F. The ALD1726E/ALD1726 is designed for use in low voltage, micropower circuits. The maximum operating voltage during normal operation should remain below 10 Volts at all times. Care should be taken to insure that the application in which the device is used do not experience any positive or negative transient voltages that will cause any of the terminal voltages to exceed this limit.

G. All inputs or unused pins except VE1 and VE2 pins should be connected to a supply voltage such as Ground so that they do not become floating pins, since input impedance at these pins is very high. If any of these pins are left undefined, they may cause unwanted oscillation or intermittent excessive current drain. As these devices are built with CMOS technology, normal operating and storage temperature limits, ESD and latchup handling precautions pertaining to CMOS device handling should be observed.